

# DS90LV011AQ Automotive LVDS Differential Driver

#### **General Description**

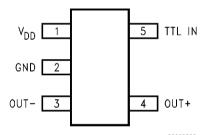
The DS90LV011AQ is an LVDS driver optimized for high data rate and low power applications. The DS90LV011AQ is a current mode driver allowing power dissipation to remain low even at high frequency. In addition, the short circuit fault current is also minimized. The device is designed to support data rates in excess of 400Mbps (200MHz) utilizing Low Voltage Differential Signaling (LVDS) technology.

The device is offered in a 5-lead small outline transistor package. The LVDS outputs have been arranged for easy PCB layout. The differential driver outputs provide low EMI with its typical low output swing of 350 mV. The DS90LV011AQ can be paired with its companion single line receiver, the DS90LT012AQ, or with any of National's LVDS receivers, to provide a high-speed LVDS interface.

#### **Features**

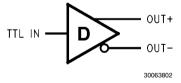
- AECQ-100 Grade 3
- Conforms to TIA/EIA-644-A Standard
- >400Mbps (200MHz) switching rates
- 700 ps (100 ps typical) maximum differential skew
- 1.5 ns maximum propagation delay
- Single 3.3V power supply
- ±350 mV differential signaling
- Power Off Protection (outputs in TRI-STATE)
- Pinout simplifies PCB layout
- Low power dissipation (23 mW @ 3.3V typical)
- SOT-23 5-lead package
- Pin compatible with SN65LVDS1

#### **Connection Diagram**



(Top View)
Order Number DS90LV011AQMF
See NS Package Number MF05A

## **Functional Diagram**



### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage ( $V_{DD}$ ) -0.3V to 4.0V LVCMOS input voltage (TTL IN) -0.3V to to ( $V_{DD}$  + 0.3V) LVDS output voltage (OUT±) -0.3V to +3.9V LVDS output short circuit current 24mA

Maximum Package Power Dissipation @ +25°C

MF Package 344 mW

Derate MF Package 7.22 mW/°C above +25°C

Thermal resistance ( $\theta_{JA}$ ) 232.5°C/Watt Thermal resistance ( $\theta_{JC}$ ) 107.0°C/Watt Storage Temperature -65°C to +150°C

Lead Temperature Range Soldering

EIAJ (0 Ω, 200 pF)

CDM (0 Ω, 0 pF)

(4 sec.) +260°C Maximum Junction Temperature +105°C ESD Ratings HBM (1.5 kΩ, 100 pF)  $\geq$  8kV

≥ 250V

≥ 1250V

## Recommended Operating Conditions

|                                   | Min | Тур | Max | Units |
|-----------------------------------|-----|-----|-----|-------|
| Supply Voltage (V <sub>DD</sub> ) | 3.0 | 3.3 | 3.6 | V     |
| Temperature (T <sub>A</sub> )     | -40 | +25 | +85 | °C    |

#### **Electrical Characteristics**

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified. (Notes 2, 3, 8)

| Symbol             | Parameter   | Conditions                                   |                          | Pin             | Min   | Тур        | Max      | Units |
|--------------------|---|--|--------------------------|-----------------|-------|------------|----------|-------|
| IV <sub>OD</sub> I | Output Differential Voltage                           | $R_L = 100\Omega$                            |                          | OUT+,           | 250   | 350        | 450      | mV    |
| $\Delta V_{OD}$    | V <sub>OD</sub> Magnitude Change                      | (Figure 1 and Figure 2)                      |                          | OUT-            |       | 3          | 35       | mV    |
| V <sub>OS</sub>    | Offset Voltage  | $R_L = 100\Omega$                            |                          | 1               | 1.125 | 1.22       | 1.375    | V     |
| ΔV <sub>OS</sub>   | Offset Magnitude Change                               | (Figure 1)                                   |                          |                 | 0     | 1          | 25       | mV    |
| I <sub>OFF</sub>   | Power-off Leakage                                     | $V_{OUT} = 3.6V$ or GND, $V_{DD} = 0V$       |                          | 1               |       | ±1         | ±10      | μA    |
| I <sub>os</sub>    | Output Short Circuit Current (Note 4)                 | V <sub>OUT+</sub> and V <sub>OUT-</sub> = 0V |                          |                 |       | -6         | -24      | mA    |
| I <sub>OSD</sub>   | Differential Output Short Circuit<br>Current (Note 4) | V <sub>OD</sub> = 0V                         |                          |                 |       | <b>-</b> 5 | -12      | mA    |
| C <sub>OUT</sub>   | Output Capacitance                                    |  |                          | ]               |       | 3          |          | pF    |
| V <sub>IH</sub>    | Input High Voltage                                    |  |                          | TTL IN          | 2.0   |            | $V_{DD}$ | V     |
| V <sub>IL</sub>    | Input Low Voltage                                     |  |                          |                 | GND   |            | 0.8      | V     |
| I <sub>IH</sub>    | Input High Current                                    | V <sub>IN</sub> = 3.3V or 2.4V               |                          |                 |       | ±2         | ±10      | μΑ    |
| I <sub>IL</sub>    | Input Low Current                                     | V <sub>IN</sub> = GND or 0.5V                |                          |                 |       | ±1         | ±10      | μΑ    |
| V <sub>CL</sub>    | Input Clamp Voltage                                   | I <sub>CL</sub> = -18 mA                     |                          |                 | -1.5  | -0.6       |          | ٧     |
| C <sub>IN</sub>    | Input Capacitance                                     |  |                          |                 |       | 3          |          | pF    |
| I <sub>DD</sub>    | Power Supply Current                                  | No Load                                      | $V_{IN} = V_{DD}$ or GND | V <sub>DD</sub> |       | 5          | 8        | mA    |
|                    |   | $R_L = 100\Omega$                            |                          |                 |       | 7          | 10       | mA    |

## **Switching Characteristics**

Over Supply Voltage and Operating Temperature Ranges, unless otherwise specified. (Notes 3, 5, 6, 7)

| Symbol            | Parameter   | Conditions                     | Min | Тур | Max | Units |
|-------------------|---|--------------------------------|-----|-----|-----|-------|
| t <sub>PHLD</sub> | Differential Propagation Delay High to Low                                | $R_L = 100\Omega, C_L = 15 pF$ | 0.3 | 1.0 | 1.5 | ns    |
| t <sub>PLHD</sub> | Differential Propagation Delay Low to High                                | (Figure 3 and Figure 4)        | 0.3 | 1.1 | 1.5 | ns    |
| t <sub>SKD1</sub> | Differential Pulse Skew It <sub>PHLD</sub> – t <sub>PLHD</sub> I (Note 9) |                                | 0   | 0.1 | 0.7 | ns    |
| t <sub>SKD3</sub> | Differential Part to Part Skew (Note 10)                                  |                                | 0   | 0.2 | 1.0 | ns    |
| t <sub>SKD4</sub> | Differential Part to Part Skew (Note 11)                                  |                                | 0   | 0.4 | 1.2 | ns    |
| t <sub>TLH</sub>  | Transition Low to High Time   |                                | 0.2 | 0.5 | 1.0 | ns    |
| t <sub>THL</sub>  | Transition High to Low Time   |                                | 0.2 | 0.5 | 1.0 | ns    |
| f <sub>MAX</sub>  | Maximum Operating Frequency (Note 12)                                     |                                |     | 250 |     | MHz   |

www.national.com 2

- **Note 1:** "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" specifies conditions of device operation.
- Note 2: Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except V<sub>OD</sub>.
- **Note 3:** All typicals are given for:  $V_{DD} = +3.3V$  and  $T_A = +25$ °C.
- Note 4: Output short circuit current (I<sub>OS</sub>) is specified as magnitude only, minus sign indicates direction only.
- Note 5: These parameters are guaranteed by design. The limits are based on statistical analysis of the device performance over PVT (process, voltage, temperature) ranges.
- Note 6: C<sub>1</sub> includes probe and fixture capacitance.
- Note 7: Generator waveform for all tests unless otherwise specified: f = 1 MHz,  $Z_0 = 50\Omega$ ,  $t_r \le 1$  ns,  $t_i \le 1$  ns (10%-90%).
- Note 8: The DS90LV011AQ is a current mode device and only function with datasheet specification when a resistive load is applied to the drivers outputs.
- Note 9:  $t_{SKD1}$ ,  $|t_{PHLD} t_{PLHD}|$ , is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel
- Note 10: t<sub>SKD3</sub>, Differential Part to Part Skew, is defined as the difference between the minimum and maximum specified differential propagation delays. This specification applies to devices at the same V<sub>DD</sub> and within 5°C of each other within the operating temperature range.
- Note 11: t<sub>SKD4</sub>, part to part skew, is the differential channel to channel skew of any event between devices. This specification applies to devices over recommended operating temperature and voltage ranges, and across process distribution. t<sub>SKD4</sub> is defined as IMax MinI differential propagation delay.
- Note 12:  $f_{MAX}$  generator input conditions:  $f_r = f_t < 1$  ns (0% to 100%), 50% duty cycle, 0V to 3V. Output criteria: duty cycle = 45%/55%,  $V_{OD} > 250$ mV.

#### **Parameter Measurement Information**

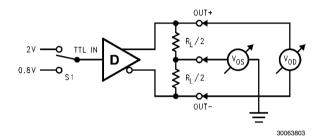


FIGURE 1. Differential Driver DC Test Circuit

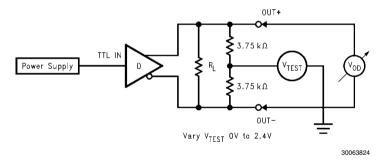


FIGURE 2. Differential Driver Full Load DC Test Circuit

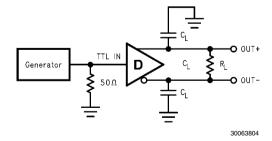


FIGURE 3. Differential Driver Propagation Delay and Transition Time Test Circuit

3 www.national.com

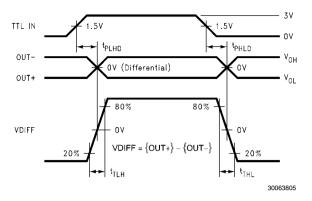


FIGURE 4. Differential Driver Propagation Delay and Transition Time Waveforms

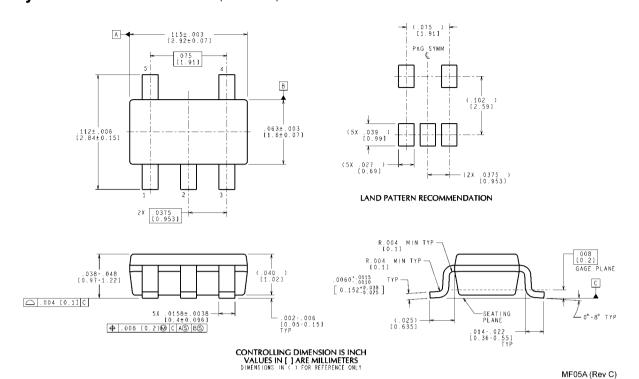
## **Application Information**

**TABLE 1. Device Pin Descriptions** 

| Package Pin Number | Pin Name        | Description                     |  |
|--------------------|-----------------|---------------------------------|--|
| SOT23              | 7 Pin Name      | Description                     |  |
| 5                  | TTL IN          | LVTTL/LVCMOS driver input pins  |  |
| 4                  | OUT+            | Non-inverting driver output pin |  |
| 3                  | OUT-            | Inverting driver output pin     |  |
| 2                  | GND             | Ground pin                      |  |
| 1                  | V <sub>DD</sub> | Power supply pin, +3.3V ± 0.3V  |  |

www.national.com

## Physical Dimensions inches (millimeters) unless otherwise noted



5-Lead SOT23, JEDEC MO-178, 1.6mm Order Number DS90LV011AQMF NS Package Number MF05A

#### **Notes**

For more National Semiconductor product information and proven design tools, visit the following Web sites at:

| Products                       |                              | Design Support          |                                |  |
|--------------------------------|------------------------------|-------------------------|--------------------------------|--|
| Amplifiers                     | www.national.com/amplifiers  | WEBENCH                 | www.national.com/webench       |  |
| Audio                          | www.national.com/audio       | Analog University       | www.national.com/AU            |  |
| Clock Conditioners             | www.national.com/timing      | App Notes               | www.national.com/appnotes      |  |
| Data Converters                | www.national.com/adc         | Distributors            | www.national.com/contacts      |  |
| Displays                       | www.national.com/displays    | Green Compliance        | www.national.com/quality/green |  |
| Ethernet                       | www.national.com/ethernet    | Packaging               | www.national.com/packaging     |  |
| Interface                      | www.national.com/interface   | Quality and Reliability | www.national.com/quality       |  |
| LVDS                           | www.national.com/lvds        | Reference Designs       | www.national.com/refdesigns    |  |
| Power Management               | www.national.com/power       | Feedback                | www.national.com/feedback      |  |
| Switching Regulators           | www.national.com/switchers   |                         |                                |  |
| LDOs                           | www.national.com/ldo         |                         |                                |  |
| LED Lighting                   | www.national.com/led         |                         |                                |  |
| PowerWise                      | www.national.com/powerwise   |                         |                                |  |
| Serial Digital Interface (SDI) | www.national.com/sdi         |                         |                                |  |
| Temperature Sensors            | www.national.com/tempsensors |                         |                                |  |
| Wireless (PLL/VCO)             | www.national.com/wireless    |                         |                                |  |

THE CONTENTS OF THIS DOCUMENT ARE PROVIDED IN CONNECTION WITH NATIONAL SEMICONDUCTOR CORPORATION ("NATIONAL") PRODUCTS. NATIONAL MAKES NO REPRESENTATIONS OR WARRANTIES WITH RESPECT TO THE ACCURACY OR COMPLETENESS OF THE CONTENTS OF THIS PUBLICATION AND RESERVES THE RIGHT TO MAKE CHANGES TO SPECIFICATIONS AND PRODUCT DESCRIPTIONS AT ANY TIME WITHOUT NOTICE. NO LICENSE, WHETHER EXPRESS, IMPLIED, ARISING BY ESTOPPEL OR OTHERWISE, TO ANY INTELLECTUAL PROPERTY RIGHTS IS GRANTED BY THIS DOCUMENT.

TESTING AND OTHER QUALITY CONTROLS ARE USED TO THE EXTENT NATIONAL DEEMS NECESSARY TO SUPPORT NATIONAL'S PRODUCT WARRANTY. EXCEPT WHERE MANDATED BY GOVERNMENT REQUIREMENTS, TESTING OF ALL PARAMETERS OF EACH PRODUCT IS NOT NECESSARILY PERFORMED. NATIONAL ASSUMES NO LIABILITY FOR APPLICATIONS ASSISTANCE OR BUYER PRODUCT DESIGN. BUYERS ARE RESPONSIBLE FOR THEIR PRODUCTS AND APPLICATIONS USING NATIONAL COMPONENTS. PRIOR TO USING OR DISTRIBUTING ANY PRODUCTS THAT INCLUDE NATIONAL COMPONENTS, BUYERS SHOULD PROVIDE ADEQUATE DESIGN, TESTING AND OPERATING SAFEGUARDS.

EXCEPT AS PROVIDED IN NATIONAL'S TERMS AND CONDITIONS OF SALE FOR SUCH PRODUCTS, NATIONAL ASSUMES NO LIABILITY WHATSOEVER, AND NATIONAL DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY RELATING TO THE SALE AND/OR USE OF NATIONAL PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

#### LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS PRIOR WRITTEN APPROVAL OF THE CHIEF EXECUTIVE OFFICER AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

Life support devices or systems are devices which (a) are intended for surgical implant into the body, or (b) support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in a significant injury to the user. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness.

National Semiconductor and the National Semiconductor logo are registered trademarks of National Semiconductor Corporation. All other brand or product names may be trademarks or registered trademarks of their respective holders.

Copyright© 2008 National Semiconductor Corporation

For the most current product information visit us at www.national.com



National Semiconductor Americas Technical Support Center Email: support@nsc.com Tel: 1-800-272-9959 National Semiconductor Europe Technical Support Center Email: europe.support@nsc.com German Tel: +49 (0) 180 5010 771 English Tel: +44 (0) 870 850 4288 National Semiconductor Asia Pacific Technical Support Center Email: ap.support@nsc.com National Semiconductor Japan Technical Support Center Email: ipn.feedback@nsc.com